# MPPS™ Miniature Package Power Solutions DUAL 40V PNP LOW SATURATION TRANSISTOR

### **SUMMARY**

PNP —  $V_{CEO} = -40V$ ;  $R_{SAT} = 104m\Omega$ ;  $I_{C} = -3A$ 

### **DESCRIPTION**

Packaged in the new innovative 3mm x 2mm MLP (Micro Leaded Package) outline, these new 4<sup>th</sup> generation low saturation dual PNP transistors offer extremely low on state losses making them ideal for use in DC-DC circuits and various driving and power management functions.

Additionally users gain several other key benefits:

Performance capability equivalent to much larger packages
Improved circuit efficiency & power levels
PCB area and device placement savings
Lower Package Height (0.9mm nom)
Reduced component count



**MLP832** 

### **FEATURES**

- Low Equivalent On Resistance
- Extremely Low Saturation Voltage (-220mV max @1A)
- h<sub>FF</sub> specified up to -3A
- I<sub>C</sub> = -3A Continuous Collector Current
- 3mm x 2mm MLP

### **APPLICATIONS**

- DC DC Converters
- Charging circuits
- Power switches
- Motor control
- CCFL Backlighting

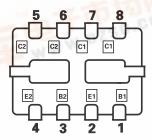
# B2 C2

### ORDERING INFORMATION

DEVICE	REEL SIZE	TAPE WIDTH	QUANTITY PER REEL
ZXTD3M832TA	7"	8mm	3000
ZXTD3M832TC	13"	8mm	10000

# DEVICE MARKING

• D33



Underside view



**ZETEX** 

### **ABSOLUTE MAXIMUM RATINGS**

PARAMETER	SYMBOL	LIMIT	UNIT
Collector-Base Voltage	V <sub>CBO</sub>	-50	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-40	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7.5	V
Peak Pulse Current	I <sub>CM</sub>	-4	А
Continuous Collector Current <sup>(a) (f)</sup>	I <sub>C</sub>	-3	А
Base Current	I <sub>B</sub>	-1000	mA
Power Dissipation at TA=25°C <sup>(a)(f)</sup> Linear Derating Factor	P <sub>D</sub>	1.5 12	W mW/°C
Power Dissipation at TA=25°C (b)(f) Linear Derating Factor	P <sub>D</sub>	2.45 19.6	W mW/°C
Power Dissipation at TA=25°C (c)(f) Linear Derating Factor	$P_{D}$	1 8	W mW/°C
Power Dissipation at TA=25°C (d)(f) Linear Derating Factor	P <sub>D</sub>	1.13 9	W mW/°C
Power Dissipation at TA=25°C <sup>(d)(g)</sup> Linear Derating Factor	P <sub>D</sub>	1.7 13.6	W mW/°C
Power Dissipation at TA=25°C <sup>(e)(g)</sup> Linear Derating Factor	P <sub>D</sub>	3 24	W mW/°C
Operating & Storage Temperature Range	T <sub>j</sub> :T <sub>stg</sub>	-55 to +150	°C
Junction Temperature	Tj	150	°C

### THERMAL RESISTANCE

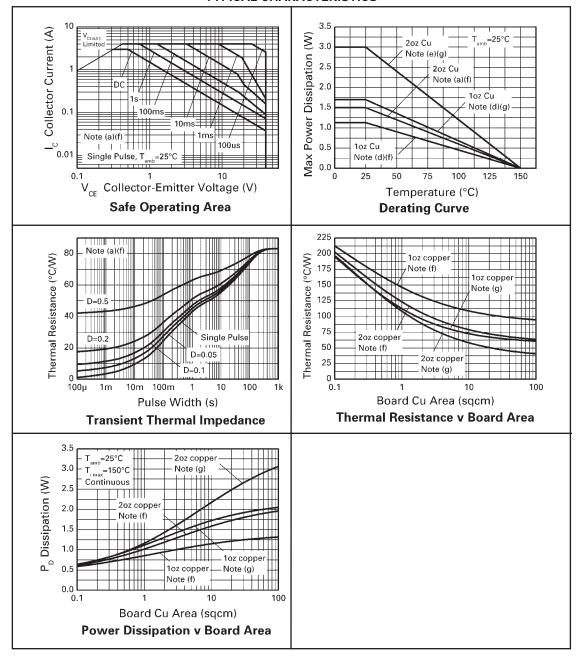
SYMBOL	VALUE	UNIT
$R_{\Theta JA}$	83.3	°C/W
$R_{\Theta JA}$	51	°C/W
$R_{\Theta JA}$	125	°C/W
$R_{\Theta JA}$	111	°C/W
$R_{\Theta JA}$	73.5	°C/W
$R_{\Theta JA}$	41.7	°C/W
	$\begin{array}{c} R_{\Theta JA} \\ R_{\Theta JA} \\ R_{\Theta JA} \\ R_{\Theta JA} \\ R_{\Theta JA} \end{array}$	R <sub>θJA</sub> 83.3 R <sub>θJA</sub> 51 R <sub>θJA</sub> 125 R <sub>θJA</sub> 111 R <sub>θJA</sub> 73.5

### NOTES

- (a) For a dual device surface mounted on 8 sq cm single sided 2oz copper on FR4 PCB, in still air conditions with all exposed pads attached. The copper area is split down the centre line into two separate areas with one half connected to each half of the dual device.
- (b) Measured at t<5 secs for a dual device surface mounted on 8 sq cm single sided 2oz copper on FR4 PCB, in still air conditions with all exposed pads attached. The copper area is split down the centre line into two separate areas with one half connected to each half of the dual device.
- (c) For a dual device surface mounted on 8 sq cm single sided 2oz copper FR4 PCB, in still air conditions with minimal lead connections only.
- (d) For a dual device surface mounted on 10 sq cm single sided 10z copper FR4 PCB, in still alir conditions with all exposed pads attached. The copper area is split down the centre line into two separate areas with one half connected to each half of the dual device.
- (e) For a dual device surface mounted on 85 sq cm single sided 2oz copper FR4 PCB, in still air conditions with all exposed pads attached. The copper area is split down the centre line into two separate areas with one half connected to each half of the dual device.
- (f) For dual device with one active die.
- (g) For dual device with 2 active die running at equal power.
- (h) Repetitive rating pulse width limited by max junction temperature. Refer to Transient Thermal Impedance graph.
- (i) The minimum copper dimensions required for mounting are no smaller than the exposed metal pads on the base of the device as shown in the package dimensions data. The thermal resistance for a dual device mounted on 1.5mm thick FR4 board using minimum copper of 1 oz weight, 1mm wide tracks and one half of the device active is Rth= 250°C/W giving a power rating of Ptot=500mW



### TYPICAL CHARACTERISTICS





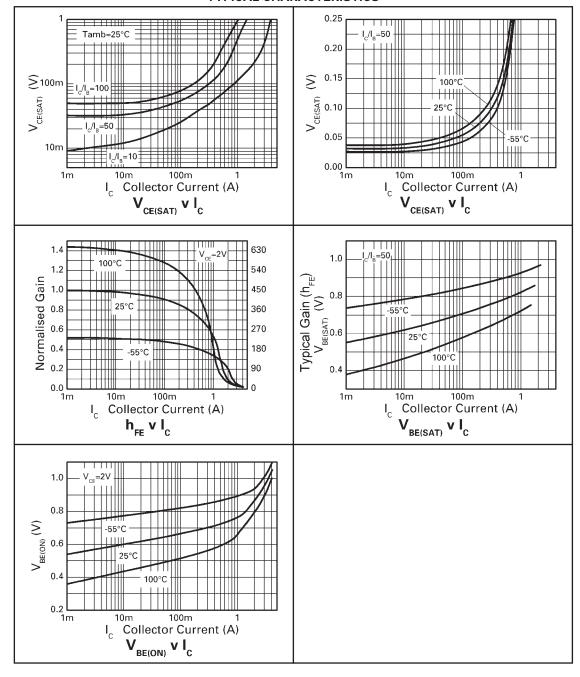
# **PNP TRANSISTOR ELECTRICAL CHARACTERISTICS** (at $T_{amb} = 25$ °C unless otherwise stated)

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	-50	-80		V	I <sub>C</sub> =-100μA
Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	-40	-70		V	I <sub>C</sub> =-10mA*
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	-7.5	-8.5		V	I <sub>E</sub> =-100μA
Collector Cut-Off Current	I <sub>CBO</sub>			-25	nA	V <sub>CB</sub> =-40V
Emitter Cut-Off Current	I <sub>EBO</sub>			-25	nA	V <sub>EB</sub> =-6V
Collector Emitter Cut-Off Current	I <sub>CES</sub>			-25	nA	V <sub>CES</sub> =-32V
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>		-25 -150 -195 -210 -260	-40 -220 -300 -300 -370	mV mV mV mV	I <sub>C</sub> =-0.1A, I <sub>B</sub> =-10mA* I <sub>C</sub> =-1A, I <sub>B</sub> =-50mA* I <sub>C</sub> =-1.5A, I <sub>B</sub> =-100mA* I <sub>C</sub> =-2A, I <sub>B</sub> =-200mA* I <sub>C</sub> =-2.5A, I <sub>B</sub> =-250mA*
Base-Emitter Saturation Voltage	V <sub>BE(sat)</sub>		-0.97	-1.05	V	I <sub>C</sub> =-2.5A, I <sub>B</sub> =-250mA*
Base-Emitter Turn-On Voltage	V <sub>BE(on)</sub>		-0.89	-0.95	V	I <sub>C</sub> =-2.5A, V <sub>CE</sub> =-2V*
Static Forward Current Transfer Ratio	h <sub>FE</sub>	300 300 180 60 12	480 450 290 130 22			I <sub>C</sub> =-10mA, V <sub>CE</sub> =-2V* I <sub>C</sub> =-0.1A, V <sub>CE</sub> =-2V* I <sub>C</sub> =-1A, V <sub>CE</sub> =-2V* I <sub>C</sub> =-1.5A, V <sub>CE</sub> =2V* I <sub>C</sub> =-3A, V <sub>CE</sub> =-2V*
Transition Frequency	f <sub>T</sub>	150	190		MHz	I <sub>C</sub> =-50mA, V <sub>CE</sub> =-10V f=100MHz
Output Capacitance	C <sub>obo</sub>		19	25	pF	V <sub>CB</sub> =-10A, f=1MHz
Turn-On Time	t <sub>(on)</sub>		40		ns	V <sub>CC</sub> =-15V, I <sub>C</sub> =-0.75A
Turn-Off Time	t <sub>(off)</sub>		435		ns	I <sub>B1</sub> =I <sub>B2</sub> =-15mA

<sup>\*</sup>Measured under pulsed conditions. Pulse width=300  $\mu s.$  Duty cycle  $\leq 2\%$ 

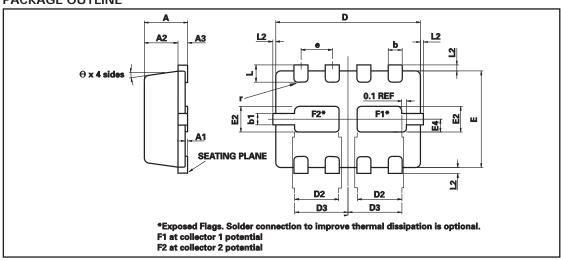


### TYPICAL CHARACTERISTICS





### **PACKAGE OUTLINE**



Controlling dimensions are in millimetres. Approximate conversions are given in inches

### **PACKAGE DIMENSIONS**

DIM	Millin	netres	Inc	hes	DIM	Millimetres		Inches	
DIIVI	Min	Max	Min	Max	DIIVI	Min	Max	Min	Max
Α	0.80	1.00	0.031	0.039	е	0.65 REF		0.0256 BSC	
A1	0.00	0.05	0.00	0.002	Ε	2.00 BSC		0.0787 BSC	
A2	0.65	0.75	0.0255	0.0295	E2	0.43	0.63	0.017	0.0249
A3	0.15	0.25	0.006	0.0098	E4	0.16	0.36	0.006	0.014
b	0.24	0.34	0.009	0.013	L	0.20	0.45	0.0078	0.0157
b1	0.17	0.30	0.0066	0.0118	L2	_	0.125	0.00	0.005
D	3.00	3.00 BSC		0.118 BSC r		0.075 BSC		0.0	029
D2	0.82	1.02	0.032	0.040	θ	0°	12°	0°	12°
D3	1.01	1.21	0.0397	0.0476					

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